

**RECEIVED  
CENTRAL FAX CENTER**Attorney Docket No. **10112501****OCT 25 2005****PATENT****IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**Applicant: **Ming-Cheng CHANG, Yi-Nan  
CHEN, Tse-Yao HUANG**Filed: **7/18/2003**Appl. No.: **10/622,965**Examiner: **Gourdreau, George**Conf. No.: **4018**Art Unit: **1763**Title: **DEEP TRENCH SELF-ALIGNMENT PROCESS FOR AN ACTIVE AREA OF  
A PARTIAL VERTICAL CELL**Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450**DECLARATION UNDER 37 CFR 1.132**

The undersigned do hereby declare:

1. I am one of the co-inventors in the above-identified application.
2. I am one of the co-inventors of US 6,909,136, issued on June 21, 2005.
3. The subject matter disclosed in column 3, line 53 to column 5, line 15 of US 6,909,136, and in the corresponding Figs. 1-4, describing a method of deep trench self-alignment, was derived from the inventors of the above-identified application. Jeng-Ping Lin, Chang-Rong Wu, and Hui-Min Mao were not co-inventors of said subject matter.
4. I further declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the above-referenced application or any patent issuing thereon.

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PATENT

<u>Ming-Cheng Chang</u>	<u>2005. 10. 7</u>
Ming-Cheng CHANG	DATE
<u>Yi-Nan Chen</u>	<u>October 7, 2005</u>
Yi-Nan CHEN	DATE
<u>Tse-Yao Huang</u>	<u>2005.10.7</u>
Tse-Yao HUANG	DATE

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